Supporting Information:

Synthesis and Characterization of All-conjugated Graft Copolymers Comprised of *n*-Type or *p*-Type Backbones and Poly(3-hexylthiophene) Side Chains

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Figure S4. ¹H NMR spectrum of PCTT in CDCl₃.



Figure S5. ¹H NMR spectrum of CTT-P3HT prepared in model reaction *via* externally initiated KCTP.



Figure S6. ¹H NMR spectra of CTT (above) and CTT-P3HT (below) in CDCl₃.



Figure S7. ¹H NMR spectra of PNDICTT₉₁(black) and PNDICTT₉₁-*g*-P3HT (red) in CDCl₃.



Figure S8. ¹H NMR spectra of PNDICTT₇₃ (black) and PNDICTT₇₃-g-P3HTa (red) in CDCl₃.



CDCl₃.



Figure S10. SEC traces of (A) PNDICTT₉₁-*g*-P3HT; (B) PNDICTT₇₃-*g*-P3HTa; and (C) PNDICTT₅₅-*g*-P3HT.



Figure S11. UV-vis spectra of product as indicated in CHCl₃.

Table S1. Electrical	parameters of bottom-gate FETs based graft polymers	
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CF:CB ^a	nonanneal			Annealing ^b		
8 mg/ml	μ°	I_{on}/I_{off}	V_{th}	μ^{c}	I_{on}/I_{off}	V_{th}
	$(cm^2 V^{-1} S^{-1})$			$(cm^2 V^{-1} S^{-1})$		
PNDICTT ₉₁	1.08×10^{-3}	3.82×10^{6}	30.50	2.66×10 ⁻³	8.96×10 ⁷	33.07
PCTT-g-P3HT	2.46×10 ⁻³	1.14×10^{2}	-2.07	7.91×10 ⁻³	8.12×10^2	11.90
PNDICTT ₉₁ - <i>g</i> -P3HT	8.76×10 ⁻⁴	2.22×10 ⁰	127.67	9.87×10 ⁻⁴	1.86×10^{0}	256.03
PNDICTT ₇₃ -g-P3HTa	2.78×10 ⁻⁴	1.78×10^{0}	263.77	3.47×10 ⁻⁴	2.24×10^{0}	131.71
PNDICTT ₅₅ -g-P3HT	5.53×10 ⁻⁴	2.48×10^{0}	157.81	6.03×10 ⁻⁴	2.07×10^{0}	218.14

^a device were fabricated from chloroform and chlorobenzene (95:5 in v/v) with a concentration of 7.5 mg/ml. ¹annealing at 140 $^{\circ}$ C for 1 hour. ^c charge mobility of PNDICTT₉₁ shows a *n*-type while the other samples show *p*-type molility.



Figure S12. The transfer characteristic of PCTT-*g*-P3HT (A), PNDICTT₉₁ (B), PNDICTT₉₁-*g*-P3HT(C), PNDICTT₇₃-*g*-P3HTa(D), PNDICTT₅₅-*g*-P3HT (E), and physical blend of PCTT-*g*-P3HT and PNDICTT91 (F).



Figure S13. The transfer characteristic of physical blend of PCTT-*g*-P3HT and PNDICTT₉₁.

 Table S2. Electrical parameters of bottom-gate FETs based blends of PCTT-g-P3HT

and PNDICTT₉₁.

CF	10mg/ml	μ (cm ² V ⁻¹ s ⁻¹)	I_{on}/I_{off}	V_{th}
nonanneal	р	4.74E-07	3.8E+00	75.37
	n	1.66E-04	1.1E+02	0.70
anneal	p	2.85E-06	9.3E+01	27.48
	n	1.33E-05	1.0E+03	1.71